## Supplementary Materials

## High-Performance Solar-Blind SnO<sub>2</sub> Nanowire Photodetectors Assembled using Optical Tweezers

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Figure S1. Low-resolution SEM image of  $SnO_2$  nanowires



Figure S2. The fabrication step of the electrode patterning by photolithography.



Figure S3. The SEM image of the  $SnO_2$  nanowire photodetector assembled by optical tweezers.



Figure S4. The typical I-V curve as a function of illuminated light wavelength.



Figure S5. The typical I-V curve as a function of illuminated light power density.